

# **Diode Rectifier Module**

### **FEATURES**

- · Reduced RFI and EMI
- Reduced Snubbing
- Extensive Characterization of Recovery Parameters
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



#### **APPLICATIONS**

 These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.



#### **ABSOLUTE MAXIMUM RATINGS**

| SYMBOL             | PARAMETER                       | CONDITIONS                                | VALUE               | UNIT             |
|--------------------|---------------------------------|---|---------------------|------------------|
| $V_{RRM}$          | Repetitive Peak Reverse Voltage |   | 1200                | V                |
| I <sub>F(AV)</sub> | Average Forward Current         | T <sub>C</sub> =100°C                     | 260                 | А                |
| IFSM               | Surge Forward Current           | t <sub>p</sub> =10ms,T <sub>j</sub> =25°C | 9500                | А                |
| l <sup>2</sup> t   | I <sup>2</sup> t for fusing     | t <sub>p</sub> =10ms,T <sub>j</sub> =25℃  | 451*10 <sup>3</sup> | A <sup>2</sup> S |
| V <sub>iso</sub>   | Isolated Voltage                |   | 2500                | V                |
| TJ                 | Junction Temperature            |   | -40~150             | °C               |
| T <sub>stg</sub>   | Storage Temperature Range       |   | -40~150             | $^{\circ}$ C     |

#### THERMAL CHARACTERISTICS

| SYMBOL              | PARAMETER                            | MAX | UNIT |
|---------------------|--------------------------------------|-----|------|
| R <sub>th j-c</sub> | Thermal Resistance, Junction to Case |     | °C/W |

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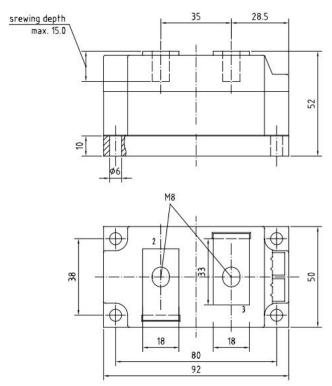
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#### **ELECTRICAL CHARACTERISTICS**

| SYMBOL          | PARAMETER                     | CONDITIONS   | MAX  | UNIT |
|-----------------|-------------------------------|--|------|------|
| V <sub>FM</sub> | Forward Voltage drop          | I <sub>F</sub> = 800A, T <sub>J</sub> = 150°C            | 1.32 | V    |
| I <sub>R</sub>  | Instantaneous Reverse Current | V <sub>R</sub> =V <sub>RRM</sub> , T <sub>J</sub> =150°C | 30   | mA   |

#### **PACKAGE OUTLINE**

Dimensions in mm (1mm = 0.0394")



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